



Full length article

MoTe₂ saturable absorber for passively Q-switched Ho,Pr:LiLuF₄ laser at ~3 μm



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ABSTRACT

Multilayer molybdenum ditelluride (MoTe₂) nanosheets were prepared by liquid-phase exfoliation (LPE) method. A YAG-based MoTe₂ saturable absorption (SA) was consequently fabricated. The MoTe₂-SA was employed in a passively Q-switched Ho,Pr:LiLuF₄ laser at 2.95 μm. Under the absorbed pump power of 3.8 W, an average output power of 90 mW was achieved. The shortest pulse duration of 670 ns was generated with an output power of 73 mW and a repetition rate of 76.46 kHz, corresponding to a pulse energy of 0.95 μJ.

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1. Introduction

Lasers operating in the mid-infrared (MIR) spectral region, the security range of the eyes, are of great interest for a comprehensive scientific and technological applications, such as air pollution monitoring, gas analysis, medical and optical space communications [1–3], since water strong absorption is about 10⁴ cm⁻¹ in this wavelength range [4].

In contrast with active Q-switching, passive Q-switching possesses several advantages: cheapness, compactness, brevity, and has been successfully applied for a wide range of pulsed lasers. Recently, graphene, topological insulators, semiconducting transition metal dichalcogenides (TMDs) and other two-dimensional materials are of great application for Q-switched lasers as saturable absorbers (SAs) in an ultrabroad spectral range, attributing to their distinctive properties [5–12]. However, graphene possesses a low modulation depth [6], topological insulators are limited to complex preparation processes [13], and black phosphorus is prone to oxidation [14]. In contrast with them, TMDs have outstanding layer-dependent semiconducting and nonlinear optical properties [15].

Compared to other semiconducting TMDs, telluride material has not attracted adequate attention. The research of MoTe₂ nanosheets is merely focused on fabrication methods and electronic properties [16–20]. In addition, MoTe₂, in contrast to MoS₂

and MoSe₂, has smaller bandgap and higher conductivity [16,21]. However, the nonlinear optical performance of MoTe₂ has not been investigated sufficiently, excepting a mode-locking Er-doped fiber laser at 1.55 μm [22]. The saturable absorption property of MoTe₂ at ~3 μm has not been reported so far.

In this contribution, a multilayer MoTe₂ nanoplatelet on a yttrium aluminum garnet (YAG) substrate was fabricated and used as saturable absorber in a Q-switched Ho,Pr:LiLuF₄ laser near 2.95 μm. Under an absorbed pump power of 3.8 W, an average output power of 90 mW was generated. The minimum pulse duration was 670 ns with a repetition rate of 76.46 kHz, corresponding to a pulse energy of 0.95 μJ. Despite somewhat low output power, it will be useful for manufacturing of ultra-compact diode pumped environmental laser sensors.

2. Preparation and characterization of MoTe₂ SA

The liquid-phase exfoliation (LPE) method was explored for fabricating MoTe₂ film [23]. The exfoliation was obtained by ultrasonically dispersing the bulk MoTe₂ in ethanol solvent for 12 h. After centrifugation at 2500 rpm for 20 min, the supernatant was transferred to another centrifuge tube for further processing. These suspensions were extraordinarily stable without precipitation after a month under ambient conditions, as shown in Fig. 1(a).

Raman spectra and atomic force microscopy (AFM) were utilized to systematically characterize the MoTe₂ samples. By using a He-Ne laser at 632.8 nm, the Raman spectra was recorded to

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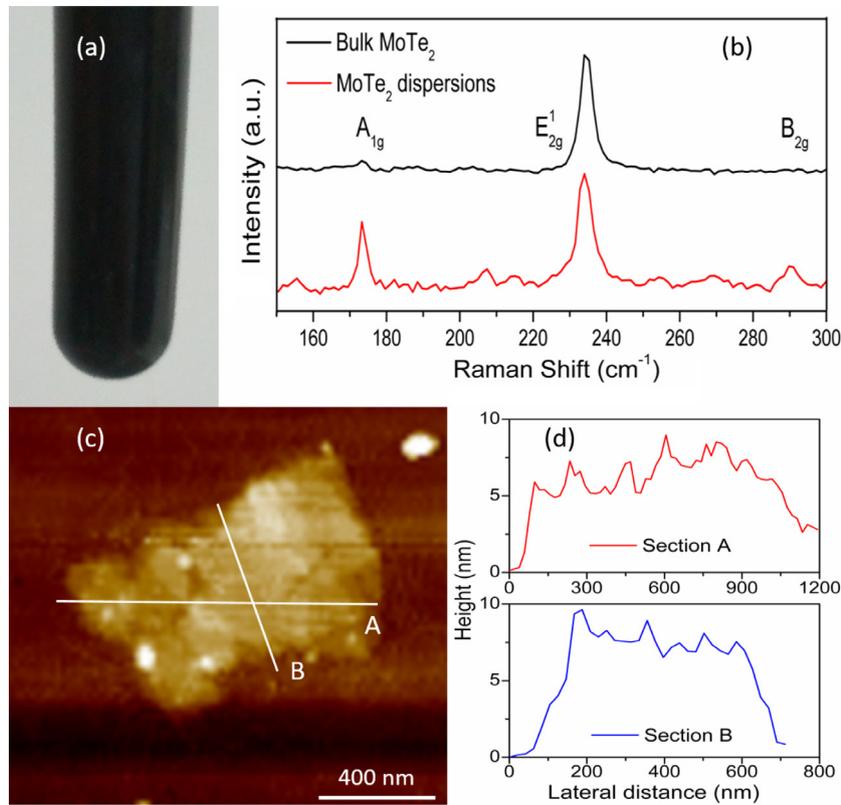


Fig. 1. (a) Suspension of the MoTe₂ nanosheet, (b) Raman spectra, (c) AFM image and (d) height variation.

prove that a multilayer structure had been successfully exfoliated from the bulk MoTe₂, the result is shown in Fig. 1(b). The characteristic vibrational modes of MoTe₂, A_{1g} at 170 cm⁻¹, E_{2g}¹ at 234 cm⁻¹, and B_{2g} at 290 cm⁻¹ were detected, while the A_{1g} mode was stronger than B_{2g} [24]. The B_{2g} mode was inactive in the bulk, however could be observed in the few-layer MoTe₂, attributing to the reduced symmetry [25]. Fig. 1(c) shows the AFM morphology of as-prepared MoTe₂-SA, which clearly reveals the MoTe₂ has been exfoliated to submicron scale sheets. Fig. 1(d) shows a height profile of section A and B in Fig. 1(c). The height of MoTe₂ thin film was estimated to be between 5 and 9.6 nm. The layer thickness was accordingly calculated to be 8–15 atomic layers, assuming the mono-layer thickness of MoTe₂ is 0.65 nm [24].

The optical transmission spectrum of the MoTe₂ film was measured from 200 nm to 3200 nm by an UV/VIS/NIR spectrophotometer (U-4100, Hitachi, Japan). A certain amount of the supernatant was dropped onto a MIR quartz plate with a dimensions of 50 mm × 20 mm, which was used as the test sample. As shown in Fig. 2, the transmission coefficient, revealing a smooth wide spectrum, increases with the augment of wavelength from the visible to mid-infrared, which may induced by the defect state, the edge state saturable absorption, or the coexistence of semiconducting and metallic states [10,26,27].

A MoTe₂-SA was prepared by dropping 5 μL dispersion onto a YAG substrate and drying in the air at room temperature. The MoTe₂-SA has a modulation depth of 22% and a saturated transmission of 88.7%, as shown in Fig. 2(inset). The surface reflection of the uncoated YAG substrate was measured to be 6.8%, which perhaps resulted from Fabry-Perot effects. Consequently, the nonsaturable loss of the MoTe₂ film is estimated to be 4.5%. The saturation fluence of the MoTe₂ nanosheet flake was calculated to be 0.14 mJ/cm².

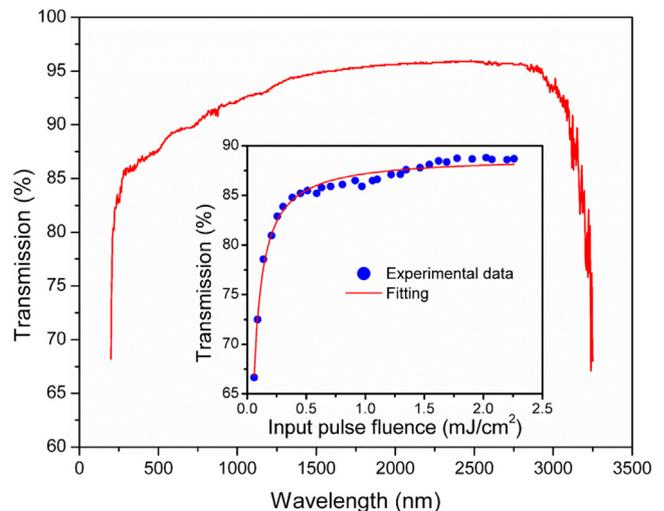


Fig. 2. Optical transmission spectrum of the MoTe₂ film; inset: nonlinear transmission of MoTe₂-SA.

3. Experiment

3.1. Experimental setup

Fig. 3 shows the schematic experimental setup of the MoTe₂ Q-switched laser with a 30 mm long plane-concave linear cavity. An uncoated Ho,Pr:LiLuF₄ crystal (2 mm × 5 mm × 10 mm) with Ho and Pr doping concentrations of 0.185 and 0.008 at.% was employed as the gain medium. The crystal was wrapped by indium foil and mounted in a copper block water-cooled to 12 °C. The pump source was a fiber-coupled laser diode emitting at 1150

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